TOSHIBA TA2009F/P

TOSHIBA BIPOLAR LINEAR INTEGRATED CIRCUIT SILICON MONOLITHIC

TA2009F, TA2009P

FILTER IC FOR Σ - Δ MODULATION SYSTEM DA CONVERTER

TA2009F, TA2009P are an analog filter IC for Σ - Δ modulation system DA converter.

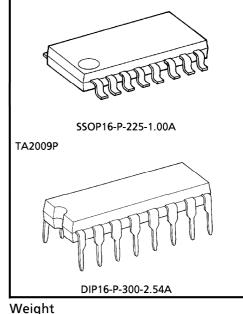
Using the TA2009F, TA2009P in combination the TC9237BF, TC9237BN (the Σ - Δ modulation system DA converter with a built-in digital filter), it is possible to construct a DA conversion system with less external parts.

FEATURES

- Built-in CR for LPFs and output (differential) amplifiers for the left and right channel.
- Single power supply operation.
- Noise distortion factor and S/N ratio are as follows (when operating at +5V single power supply):

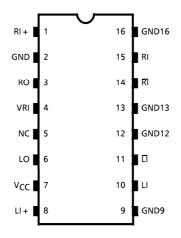
Noise distortion factor: -93dB (Typ.) S/N : 100dB (Typ.)

PIN CONNECTION (Top view)



TA2009F

SSOP16-P-225-1.00A : 0.14g (Typ.) DIP16-P-300-2.54A : 1.00g (Typ.)

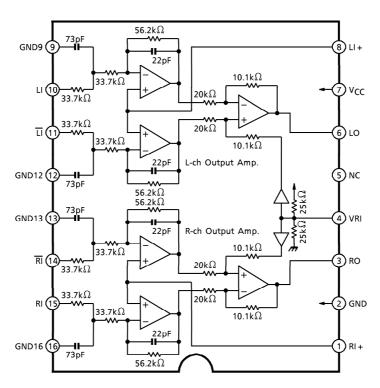


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BLOCK DIAGRAM



DESCRIPTION OF PIN FUNCTIONS

PIN No.	SYMBOL	1/0	FUNCTION & OPERATION	REMARKS			
1	RI +	I	channel operational amplifier forward input terminal. onnect to VRI.				
2	GND	_	Ground terminal.	_			
3	RO	0	R channel analog output terminal.	_			
4	VRI		Reference voltage terminal. (V _{CC} / 2)	See the block diagram			
5	NC	_	on-connecting terminal. —				
6	LO	0	. channel analog output terminal. —				
7	۷CC	_	Supply voltage terminal. —				
8	LI+	_	channel operational amplifier forward input terminal.				
9	GND9	_	Ground terminal for L channel reverse input side filter.	_			
10	LI	I	L channel forward input terminal.	Connect to LO of TC9237BF, TC9237BN			
11	ΙΪ	I	L channel reverse input terminal.	Connect to LO of TC9237BF, TC9237BN			
12	GND12	_	Ground terminal for L channel forward input side filter. —				
13	GND13	_	Ground terminal for R channel forward input side filter. —				

PIN No.	SYMBOL	1/0	FUNCTION & OPERATION	REMARKS	
14	RĪ	I	R channel reverse input terminal.	Connect to \overline{RO} of TC9237BF, TC9237BN	
15	RI	I	R channel forward input terminal.	Connect to RO of TC9237BF, TC9237BN	
16	GND16	_	Ground terminal for R channel reverse input side filter.	_	

MAXIMUM RATINGS (Ta = 25°C)

CHARACTER	ISTIC	SYMBOL	RATING	UNIT	
Supply Voltage		Vcc	11	V	
Power Dissipation	TA2009F	D-	350 (*)	mW	
Power Dissipation	TA2009P	PD	1388 (**)		
Operating Tempera	ature	T _{opr}	- 35∼85	°C	
Storage Temperatu	re	T _{stg}	- 55∼150	°C	

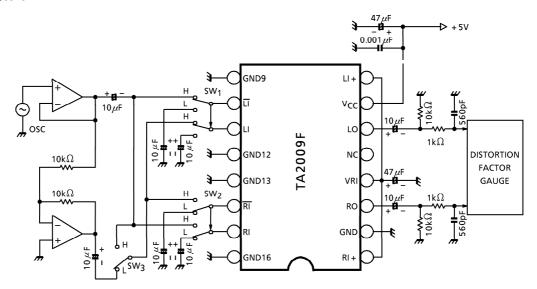
- (*) Reduce $2.8 \text{mW}/^{\circ}\text{C}$ at $Ta = above 25^{\circ}\text{C}$.
- (**) Reduce $11.2 \text{mW} / ^{\circ}\text{C}$ at $Ta = above 25 ^{\circ}\text{C}$.

ELECTRICAL CHARACTERISTICS (Unless otherwise specified, V_{CC} = 5V, Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CIR- CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Operating Supply Voltage	Vcc	_	Ta = −35~85°C	4.5	5.0	10	V
Operating Supply	Iccq (1)		At no signal	7.5	10.0	12.5	mA
Current	IccQ (2)		At signal, $V_{CC} = 10V$	8.2	11.0	13.8	IIIA
Reference Voltage	VRI	_	_	2.45	2.50	2.55	V
	THD (1)	1	$1kHz$, $V_0 = 970 \text{mV}_{rms}$	_	- 93	- 90	dB
Noise Distortion Factor	THD (2)		10kHz, $V_0 = 970 \text{mV}_{rms}$	_	- 93	- 90	
	THD (3)		1kHz, $V_0 = 97 \text{mV}_{rms}$	_	- 78	- 75	
Cross Talk	CT	1	1kHz, $V_0 = 970 \text{mV}_{rms}$	_	- 100	- 95	dB
A44	ATT (1)	1	$40kHz$, $V_0 = 10dBV_{rms}$	0.51	0.71	1.41	dB
Attenuation	ATT (2)		80kHz, $V_0 = 10$ dB V_{rms}	1.50	2.70	4.50	
Max. Output Level	V _{omax}	1	1kHz, THD = 1%	1.20	1.25	_	V _{rms}
Differential Balance	G _{VB}	1	1kHz, 1.1dBV _{rms} In-phase input	_	_	- 40	dB
LR Output Difference	G _{VD}	1	1kHz, 1.1dBV _{rms} Differential input	_	0	0.5	dB

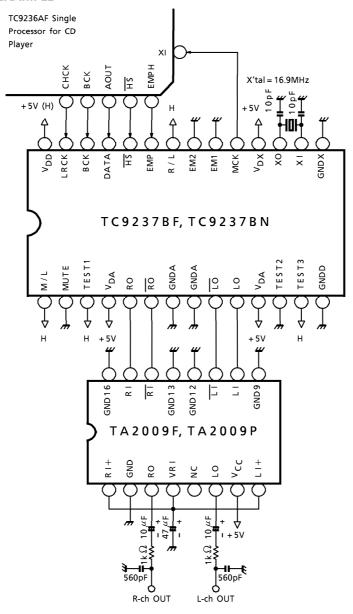
- (Note 1) When the TC9237BF, C9237BN and +5V single power supply are operated : Full scale = 970mV_{rms} (Typ.).
- (Note 2) Measuring circuit-1: indicates the measuring circuit.

TEST CIRCUIT-1



sw ₁	SW ₂	SW ₃	MEASURING ITEM
L	L	_	Operating supply voltage, Reference voltage
L	Н	L	Cross talk (R→L)
Н	L	L	Cross talk (L→R)
н н		L	Noise distortion factor, Attenuation, Maximum output
			level, LR output difference
Н	Н	Н	Difference balance

APPLICATION CIRCUIT EXAMPLE



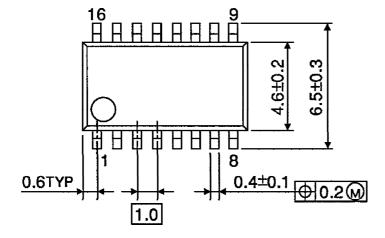
(Cautions)

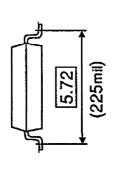
- Quality of crystal oscillation waveform largely effects S/N ratio.
 Further, this is also true when system clock is input externally through the XI terminal of pin[®].
- Suppress glitch of input signals (LRCK, BCK, DATA) as could as possible.
- The wiring between the TC9237BF, TC9237BN output and the analog filter amplifier input must be made the shortest
- The capacitor between VDA and GNDA shall be connected as close to the pin as possible.

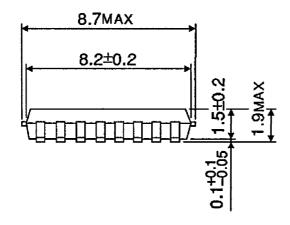
Unit: mm

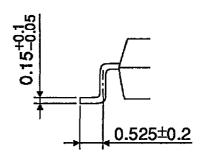
OUTLINE DRAWING

SSOP16-P-225-1.00A





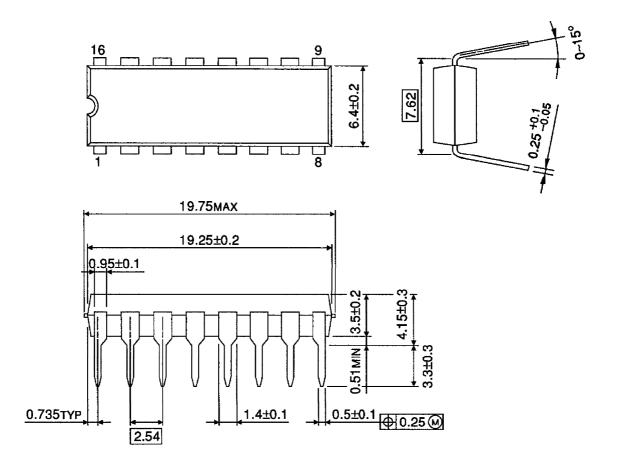




Weight: 0.14g (Typ.)

OUTLINE DRAWING DIP16-P-300-2.54A

Unit: mm



Weight: 1.00g (Typ.)